SENSITRON

MBR120HW-G/ MBR140HW-G

SEMICONDUCTOR

SURFACE MOUNT SCHOTTKY BARRIER DIODE

Data Sheet 3344, Rev. — Features

Green Products

Low Turn-on Voltage

- Fast Switching
- PN Junction Guard Ring for Transient and ESD Protection
- Designed for Surface Mount Application
- Plastic Material UL Recognition Flammability Classification 94V-O
- Green Products in Compliance with the RoHS Directive

Directive B

Dim Min Max Min Max 3.6 0.14 0.154 3.9 В 2.5 2.8 0.098 0.110 С 1.4 1.8 0.055 0.070 0.5 0.7 0.020 0.028 Ε 0.2 0.008 G 0.4 0.016 1.35 0.053 Н 0.95 0.037 J 0.12 0.005 In mm In inch

SOD-123

Mechanical Data

- Case: SOD-123, Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: Cathode Band
- Weight: 0.01 grams (approx.)
- Marking: MBR120HW-G G3
 - MBR140HW-G G5

$Maximum \ Ratings \ @T_{A}\!\!=\!\!25\,\% \ unless \ otherwise \ specified$

Characteristic	Symbol	MBR120HW-G	MBR140HW -G	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	VRRM VRWM VR	20	40	V
Forward Continuous Current (Note 1)	lF	1.	.0	Α
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	IFSM	25		A
Power Dissipation (Note 1)	Pd	45	50	mW
Typical Thermal Resistance, Junction to Ambient Air (Note 1)	$R_{ heta}$ JA	22	22	°C/W
Operating and Storage Temperature Range	Тј, Тѕтс	-65 to	+125	℃

Electrical Characteristics @T_A=25 ℃ unless otherwise specified

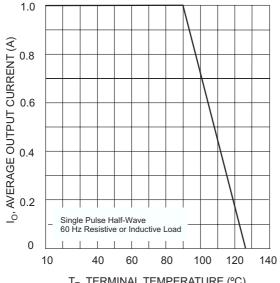
Characteristic		Symbol	MBR120HW-G	MBR140HW-G	Unit
Forward Voltage Drop	@IF = 1.0A	VFM	0.45	0.55	V
Peak Reverse Leakage Current @ DC Blocking Voltage		lгм	400	500	μΑ
Typical Junction Capacitance (VR = 4V DC, f = 1MHz)		Cj	50		рF

Note: 1. Valid provided that terminals are kept at ambient temperature.

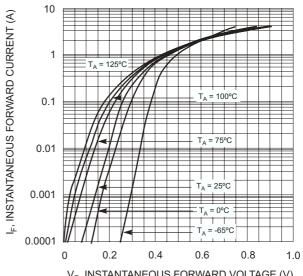
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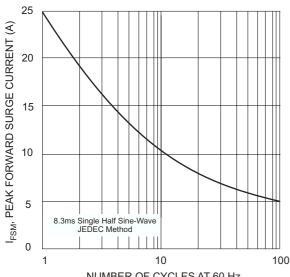
Green Products



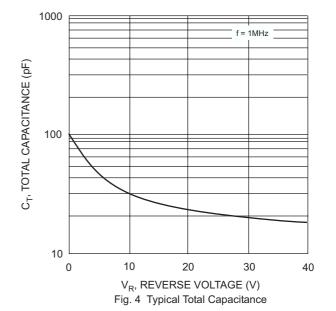
T_T, TERMINAL TEMPERATURE (°C) Fig. 1 Forward Current Derating Curve



V_F, INSTANTANEOUS FORWARD VOLTAGE (V) Fig. 2 Typical Forward Characteristics



NUMBER OF CYCLES AT 60 Hz Fig. 3 Maximum Non-Repetitive Peak Fwd Surge Current



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ORDERING INFORMATION

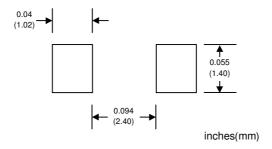
Product No•.◆	Package Type	Shipping Quantity
MBR120HW-G-T1	SOD-123	3000/Tape & Reel
MBR120HW-G-T3	SOD-123	10000/Tape & Reel
MBR140HW-G-T1	SOD-123	3000/Tape & Reel
MBR140HW-G-T3	SOD-123	10000/Tape & Reel

Products listed in bold are Sensitron Preferred devices.

T1 suffix refers to a 7" reel. T3 suffix refers to a 13" reel.

Shipping quantity given is for minimum packing quantity only. For minimum order quantity, please consult the Sales Department.

RECOMMENDED FOOTPRINT



SENSITRON SEMICONDUCTOR

MBR120HW-G/MBR140HW-G

SURFACE MOUNT SCHOTTKY BARRIER DIODE

Data Sheet 3344, Rev. —

Green Products

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